

^{213}Bi α decay 2013Ma13

Type	Author	History	Citation	Literature Cutoff Date
Full Evaluation	J. Chen [#] and F. G. Kondev	NDS 126, 373 (2015)		30-Sep-2013

Parent: ^{213}Bi : E=0.0; $J^\pi=9/2^-$; $T_{1/2}=45.61$ min 6; $Q(\alpha)=5988$ 4; $\% \alpha$ decay=2.140 10

$^{213}\text{Bi}-J^\pi$: From Adopted Levels of ^{213}Bi .

$^{213}\text{Bi}-T_{1/2}$: Weighted average of 45.59 min 6 ([1973Po16](#)) and 45.62 min 6 ([2013Ma13](#),[2013Su13](#)). Others: 47 min 1 ([1950Ha52](#)), 46 min 1 ([1964Gr11](#)) and 46 min ([1947En03](#)).

$^{213}\text{Bi}-Q(\alpha)$: From $E\alpha=5875$ 4, weighted average of 5860 30 ([1947En03](#)), 5870 6 ([1967Dz02](#)), 5869 10 ([1964Gr11](#)) and 5878 4 ([2013Ma13](#)). $Q(\text{g.s.})=5982$ 6 from [2012Wa38](#).

$^{213}\text{Bi}-\% \alpha$ decay: From a high-resolution α spectroscopy in [2013Ma13](#). Others: $\% \alpha=2.20$ 3 ([1997Ch53](#)), 2.09 3 ([1998Ar03](#)), 2.022 26 ([1986He06](#)) and 2.16 11 ([1964Gr11](#)).

[2013Ma13](#): ^{213}Bi activities were produced from an open ^{225}Ac source. α -particles were detected with a high-resolution ion-implanted planar silicon detector (PIPS). Measured $E\alpha$, $I\alpha$, $\alpha(t)$. Deduced levels, $T_{1/2}$, α -branching ratios.

[2000Gr35](#): Measured $E\gamma$, $I\gamma$, $I(x\text{-ray})$, $\gamma\gamma$ -coin, xy -coin. Deduced levels, conversion coefficients.

[1997Ch53](#): ^{213}Bi activities were produced from a ^{225}Ac source. Measured $E\alpha$, $I\alpha$.

[1989Ko26](#): ^{213}Bi activities were produced from a 20 μg ^{229}Th sample. γ -rays were detected by a 17% efficient HPGe coaxial detector (FWHM=1.9 keV at 1.33 MeV) and a 2 cm^3 LEPS (FWHM=190 eV at the Fe K_α x-line and a 8% efficient Ge(Li) detector for $\gamma\gamma$ -coincidence measurements. Measured $E\gamma$, $I\gamma$, $\gamma\gamma$ -coin. Deduced levels.

[1981Di14](#): ^{213}Bi activities were produced from a ^{229}Th sample. Measured γ -rays using a 90 cm^3 Ge(Li) detector (FWHM=3.75 keV at $E=2614$ keV) and a 200 cm^3 high-resolution intrinsic Ge detector (FWHM \approx 0.6 keV for $E<200$ keV).

[1977Vy02](#): ^{213}Bi activities were produced from a ^{221}Rn sample. Measured $E\gamma$, $I\gamma$ using Ge(Li) detectors.

Others: [2002Mo46](#), [1998MaZO](#), [1998Ar03](#), [1994Ar23](#), [1992Li26](#), [1986He06](#), [1972Dz14](#), [1969ArZV](#), [1968GuZW](#), [1967VrZZ](#), [1964Gr11](#).

 ^{209}Tl Levels

$E(\text{level})^{\dagger\ddagger}$	$J^\pi{}^{\#}$
0.0	$1/2^+$
323.70 2	$3/2^+$

[†] from a least-squares fit to $E\gamma$.

[‡] [1989Ko26](#) proposed a level at 868.3-keV based on the observation of 544.9 keV 3 and 868.0 keV 2 γ -rays. However, the later work of [1998Ar03](#) showed that 868 γ belongs to the β^- branch of ^{213}Bi , rather than to its α branch. The 544.9 γ includes a contribution from the double-escape peak of the 1567 γ in ^{209}Tl β^- decay and without the parallel 868 γ to define the level energy, the placement of the residual component of the 544.9 γ to ^{213}Bi α decay cannot be established.

[#] From Adopted Levels.

 α radiations

$E\alpha$	$E(\text{level})$	$I\alpha^{\ddagger}$	HF^{\dagger}	Comments
5558 4	323.70	8.45 11	90 9	$E\alpha$: weighted average of 5560 keV 4 (2013Ma13) and 5549 keV 10 (1964Gr11). $I\alpha$: from 2013Ma13 . Others: 6.8 1 (1997Ch53), 7.4 14 (1964Gr11).
5875 4	0.0	91.55 11	264 26	$E\alpha$: weighted average of 5860 keV 30 (1947En03), 5870 keV 6 (1967Dz02), 5869 keV 10 (1964Gr11) and 5878 keV 4 (2013Ma13). $I\alpha$: from 2013Ma13 . Others: 93.2 14 (1997Ch53), 92.6 14 (1964Gr11).

[†] $r_0(^{209}\text{Tl})=1.51$ 3, average of 1.5396 1 for ^{210}Pb (deduced from $Hf(7686.82\alpha)=1$) and 1.48 5 for ^{208}Hg , estimated from $r_0(^{206}\text{Hg})=1.45$ 4 and the systematics of [1998Ak04](#).

[‡] For absolute intensity per 100 decays, multiply by 0.02140 10.

^{213}Bi α decay 2013Ma13 (continued) $\gamma(^{209}\text{Tl})$

E_γ	$I_\gamma^\#$	$E_i(\text{level})$	J_i^π	E_f	J_f^π	Mult.	δ^\ddagger	α^\dagger	Comments
323.70 2	0.167 3	323.70	$3/2^+$	0.0	$1/2^+$	M1+E2	$1.30 +23-19$	0.174 18	$\alpha(K)=0.131\ 16; \alpha(L)=0.0330\ 15;$ $\alpha(M)=0.0080\ 3$ $\alpha(N)=0.00202\ 8; \alpha(O)=0.000377\ 17; \alpha(P)=2.80\times 10^{-5}\ 25$
$^x 544.9 @$	3	0.0167 24							E_γ : weighted average of 323.81 keV 5 (1977Vy02), 323.7 keV 2 (1981Di14), 323.71 keV 3 (1989Ko26), 323.69 keV 5 (1998Ar03), 323.69 keV 1 (1994Ar23) and 323.80 keV 4 (2000Gr35). Other measurement: 1964Gr11 . I_γ : from $I_\gamma(323\gamma)/I_\gamma(440\gamma$ in $^{213}\text{Po})=0.00639\ 12$ (weighted average of 0.0062 3 (2000Gr35), 0.0057 5 (1998Ar03), 0.0057 4 (1994Ar23), 0.0062 6 (1989Ko26) and 0.00660 15 (1981Di14)) and % $I_\gamma(440\gamma)=26.10\ 17$ (weighted average of 26.1 3 (1986He06) and 26.1 2 (2002Mo46). The latter value supersedes that of 25.4 3 (2000Gr35), which is from the same laboratory). The value of $I_\gamma(323\gamma)/I_\gamma(440\gamma$ in $^{213}\text{Po})=0.0112\ 8$ (1977Vy02) is excluded from the average, since it is much higher than others and is also superseded by 2000Gr35 . Other: % $I_\gamma=0.154\ 3$ from % $I_\alpha=8.45\ 11$, % $\alpha=2.140\ 10$ and α . Mult., δ : from $\alpha(K)\exp=0.131\ 15$ (2000Gr35). Other (from the same group): $\alpha(K)\exp=0.40\ 9$ (1998MaZO). E_γ : from 1989Ko26 . I_γ : from $I_\gamma(544.9\gamma)/I_\gamma(323.7\gamma)=0.100\ 14$ (1989Ko26) and $I_\gamma(323.7\gamma)=0.167\ 3$, as deduced in the present work.
x	γ ray not placed in level scheme.								

[†] Additional information 1.[‡] Additional information 2.

Absolute intensity per 100 decays.

@ Placement of transition in the level scheme is uncertain.

^x γ ray not placed in level scheme.

^{213}Bi α decay 2013Ma13Decay SchemeIntensities: $I_{(\gamma+ce)}$ per 100 parent decays